

E. K. ARUSHANOV

PUBLICATIONS

in refereed journals and full paper published in refereed conference proceedings

1. M. Guc, A.P. Litvinchuk, S. Levchenko, M.Ya. Valakh, I.V. Bodnar, V.M. Dzhagan, V. Izquierdo-Roca, **E. Arushanov**, A. Perez-Rodriguez, Optical phonons in the kesterite $\text{Cu}_2\text{ZnGeS}_4$ semiconductor: polarized Raman spectroscopy and first-principle calculations. *RSC Adv.* 2016, **6**, 13278-13285.
2. Maxim Guc, Sergiu Levchenko, Ivan V. Bodnar, Victor Izquierdo-Roca, Xavier Fontane, Larisa V. Volkova, **Ernest Arushanov**, Alejandro Pérez-Rodríguez, Polarized Raman scattering study of kesterite type $\text{Cu}_2\text{ZnSnS}_4$ single crystals. *Sci. Rep.* 2016, **6**, 19414/7.
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4. C.P. Weber, **Ernest Arushanov**, Bryan S. Berggren, Tahereh Hosseini, Nikolai Kouklin, Alex Nateprov, Transient reflectance of photoexcited Cd_3As_2 . *Appl. Phys. Lett.* 2015, **106**, 231904.
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6. Galina Gurieva, Sergiu Levchenko, Victor Ch. Kravtsov, Alexander Nateprov, Elisabeth Irran, Ying-Sheng Huang, **Ernest Arushanov**, Susan Schorr, X-ray diffraction investigation on $\text{Cu}_2\text{ZnSiSe}_4$ single and polycrystalline crystals. *Z. Kristallogr. - Cryst. Mater.* 2015, **230**, 507-511.
7. N.N. Syrbu, V. Zalamai, M. Guc, S. Levchenko, A. Dorogan, **E. Arushanov**, Birefringence of $\text{Cu}_2\text{ZnSiSe}_4$ single crystals. *J. Alloy Compd.* 2015, **635**, 188-193.
8. S. Levchenko, R Caballero, L. Dermenji, E.V. Telesh, I.A. Victorov, J.M. Merino, **E. Arushanov**, M. Leon, I.V. Bodnard, Preparation and optical characterization of $\text{Cu}_2\text{ZnGeSe}_4$ thin films. *Opt. Mater.* 2015, **40**, 76-80.
9. Serghei Levchenko, Alexandr Nateprov, Victor Kravtsov, Maxim Guc, Alejandro Pérez-Rodríguez, Victor Izquierdo-Roca, Xavier Fontané, **Ernest Arushanov**, Structural study and Raman scattering analysis of $\text{Cu}_2\text{ZnSiTe}_4$ bulk crystals. *Opt. Express* 2014, **22**, A1936-A1943.
10. M. León, S. Levchenko, R. Serna, I. V. Bodnar, A. Nateprov, M. Guc, G. Gurieva, N. Lopez, J.M. Merino, R. Caballero, S. Schorr, A. Perez-Rodriguez, **E. Arushanov**, Spectroscopic ellipsometry study of $\text{Cu}_2\text{ZnSnSe}_4$ bulk crystals. *Appl. Phys. Lett.* 2014, **105**, 061909/4.
11. M. Guc, A. P. Litvinchuk, S. Levchenko, V. Izquierdo-Roca, X. Fontané, M. Ya. Valakh, **E. Arushanov**, A. Pérez-Rodríguez, Optical phonons in wurtzstannite $\text{Cu}_2\text{ZnGeS}_4$ semiconductor: polarized Raman spectroscopy and first principle calculations. *Phys. Rev. B* 2014, **89**, 205205/7.

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